Synthesis, crystal structure, optical, and electronic study of the new ternary thorium selenide $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$

Jai Prakash^a, Adel Mesbah^{a,b}, Jessica Beard^a, Sébastien Lebègue^c, Christos D. Malliakas^a, and James A. Ibers^{a,*}

^a*Department of Chemistry, Northwestern University, Evanston, IL 60208-3113, USA*

^b*ICSM, UMR 5257 CEA / CNRS / UM2 / ENSCM, Site de Marcoule - Bât. 426, BP 17171, 30207 Bagnols-sur-Cèze cedex, France*

^c*Laboratoire de Cristallographie, Résonance Magnétique et Modélisations (CRM2, UMR CNRS 7036), Institut Jean Barriol, Université de Lorraine, BP 239, Boulevard des Aiguillettes, 54506 Vandoeuvre-lès-Nancy, France*

Keywords: barium thorium selenide; crystal structure; optical study; band gap; DFT

Abstract

The compound $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ has been synthesized by solid-state methods at 1173 K. Its crystal structure features one dimensional chains of $[\text{Th}(\text{Se})_3(\text{Se}_2)_2]^{6-}$ separated by Ba^{2+} cations. Each Th atom in these chains is coordinated to two Se–Se single-bonded pairs and four Se atoms to give rise to a pseudooctahedral geometry around Th. The Th–Se distances are consistent with Th^{4+} and hence charge balance of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ is achieved as $3 \times \text{Ba}^{2+}$, $1 \times \text{Th}^{4+}$, $3 \times \text{Se}^{2-}$, and $2 \times \text{Se}_2^{2-}$. From optical measurements the band gap of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ is 1.96(2) eV. DFT calculations indicate that the compound is a semiconductor.

1. Introduction

Solid-state actinide chalcogenides offer diverse crystal chemistry, different stoichiometries, and a wide range of physical properties, including optical [1-3], magnetic [1-3], and transport [4,5]. These result from the presence of f-electrons and ability of the lighter actinides (An) to show variable oxidation states, and the tendency of the heavier chalcogens (Q) to show various Q–Q interactions. The crystal chemistry and properties of Th chalcogenides are

*Corresponding author.

E-mail address: ibers@chem.northwestern.edu (J.A.Ibers)

less known than those of U chalcogenides. Examples of binary thorium chalcogenides include ThS_2 [6], Th_2S_3 [7], $\alpha\text{-ThTe}_3$ [8], Th_2Q_5 ($\text{Q} = \text{S}$ [9] and Se [10]), and Th_7Q_{12} ($\text{Q} = \text{S}$ [11] and Te [12]), although the latter two are almost certainly the ternary $\text{Th}_7\text{O}_2\text{Q}_{12}$ [13]. The crystal structures of these binary compounds range from simple layered structures as in $\alpha\text{-ThTe}_3$ to complex modulated structures as in Th_2Se_5 [10].

Ternary thorium chalcogenides involving an electropositive alkali metal (A) or alkaline-earth metal or a transition metal often show new structure types with varied physical properties. Examples of ternary thorium chalcogenides are ATh_2Q_6 ($\text{A} = \text{K}, \text{Rb}, \text{Cs}, \text{Cu}$; $\text{Q} = \text{Se}, \text{Te}$) [14-18], Ba_2ThS_6 [19], SrTh_2Se_5 [18], BaTh_2S_5 [20], MnThSe_3 [21], and $\text{Th}_{0.81}\text{Mo}_6\text{S}_8$ [22].

The few known quaternary thorium chalcogenides include ACuThQ_3 ($\text{A} = \text{K}, \text{Cs}, \text{Tl}$; $\text{Q} = \text{S}, \text{Se}$) [23-26], $\text{Ba}_2\text{Cu}_2\text{ThS}_5$ [27], $\text{Ba}_2\text{Cu}_2\text{ThSe}_5$ [28], $\text{K}_2\text{Cu}_2\text{ThS}_4$ [23], $\text{K}_3\text{Cu}_3\text{Th}_2\text{S}_7$ [23], $\text{KThSb}_2\text{Se}_6$ [29], and $\text{Ba}_2\text{CrThTe}_7$ [30].

To extend the chemistry of thorium chalcogenides, we have carried out exploratory syntheses. Here we present the synthesis, structure, optical, and electronic properties of the new thorium chalcogenide, $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$.

2. Experimental

2.1 Syntheses

Caution! ^{232}Th is an α -emitting radioisotope and as such is considered a health risk. Its use requires appropriate infrastructure and personnel trained in the handling of radioactive materials.

The starting materials Ba (Johnson Matthey, 99.5 %), Th (MP Biomedicals, 99.1 %), Sb (Alfa, 99.5 %), and Se (Cerac, 99.999 %) were used as obtained. Reactions were performed in sealed 6 mm carbon-coated fused-silica tubes. Chemical manipulations were performed inside an Ar-filled dry box. The reactants were weighed and transferred into tubes that were then evacuated to 10^{-4} Torr, flame sealed, and placed in a computer-controlled furnace.

Synthesis of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$. Dark-red block-shaped crystals of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ were initially obtained from the reaction of Ba (35.5 mg, 0.2585 mmol), Th (10 mg, 0.0431 mmol), Sb

(10.9 mg, 0.0895 mmol), and Se (54.4 mg, 0.6890 mmol). The reaction mixture was heated to 1033 K in 36 h and held constant at this temperature for 15 h. The temperature of the furnace was then raised to 1173 K at 1.5 K/h, and the reaction mixture was annealed for 96 h followed by slow cooling to 573 K at 2 K/h and then to 298 K at 11 K/h. Semi-quantitative EDX analysis of the products of the reaction were obtained with the use of a Hitachi S-3400 SEM microscope. The reaction product contained dark-red crystals of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ (Ba:Th:Se $\approx$ 3:1:7), black columnar crystals of Sb_2Se_3 [31] (Sb:Se $\approx$ 2:3), red crystals of BaSe, copper-colored crystals of Th_2Se_5 [10] (Th:Se $\approx$ 2:5), and plate-shaped red crystals of ThOSe [32]. Crystals of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ were subsequently obtained from the stoichiometric reaction of the elements using the same heating conditions. The crystals of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ stored in paratone oil were stable for months. However, crystals stored under ambient condition decomposed in a few weeks.

2.2 Crystal structure determination

The crystal structure of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ was determined from single-crystal X-ray diffraction data collected with the use of graphite-monochromatized $\text{MoK}\alpha$ radiation ($\lambda = 0.71073 \text{ \AA}$) at 100(2) K on a Bruker APEX2 diffractometer [33]. The algorithm COSMO implemented in the program APEX2 was used to establish the data collection strategy with a series of 0.3° scans in ω and φ . The exposure time was 10 s/frame and the crystal-to-detector distance was 60 mm. The collection of intensity data as well as cell refinement and data reduction were carried out with the use of the program APEX2 [33]. Face-indexed absorption, incident beam, and decay corrections were performed with the use of the program SADABS [34]. Precession images of the data set provided no evidence for a super cell or for modulation. The structure was solved and refined in a straightforward manner with the use of the SHELX-14 algorithms of the SHELXL program package [34,35]. The program STRUCTURE TIDY [36] in PLATON [37] was used to standardize the atomic positions. Further details are given in Table 1 and in the Supporting information.

2.3 Optical study

Single-crystal absorption spectra were obtained at 298 K on a Hitachi U-6000 Microscopic FT spectrophotometer mounted on an Olympus BH2-UMA microscope. A single crystal of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ was placed on a glass slide and positioned over the light source where the transmitted light was recorded from above. The background signal of the glass slide was subtracted from the collected intensity.

2.4. Theoretical calculations

Density functional theory [38,39] and the Heyd-Scuseria-Ernzerhof (HSE) [40-42] exchange-correlation functional were used for the calculations. The Vienna ab Initio Simulation Package [43,44] implementing the projector augmented wave method [45] was employed. The atomic positions and cell parameters were taken from the crystal-structure results. The Brillouin zone was sampled with a $4 \times 8 \times 6$ mesh, and the default cut-off for the plane-wave part of the wave function was used.

3. Results

3.1 Synthesis and structure of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$

Single crystals of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ were initially obtained at 1173 K in about 10 wt% yield in an attempt to discover a new quaternary compound in the Ba/Th/Sb/Se system. Synthesis of dark-red crystals of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ were reproduced by the stoichiometric reaction of the elements using the same heating conditions. However, the yield was still low (about 20 wt%) and the major products were Th_2Se_5 [10] and BaSe. Further attempts to improve the yield of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ by varying the heating conditions were unsuccessful.

A view of the crystal structure of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ is shown in Fig. 1. The compound crystallizes in a new structure type with two formula units in the noncentrosymmetric space group $C_{2v}^{20} - \text{Imm}2$ of the orthorhombic crystal system with cell constants $a = 12.4213(1)$, $b =$

5.7911(1), and $c = 9.5039(1)$ Å. Metrical data for $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ are presented in Table 2 and in the Supporting information. The asymmetric unit of the structure comprises one Th atom (site symmetry $mm2$), two Ba atoms (Ba1 ($.m.$), Ba2 ($mm2$)), and four Se atoms (Se1 ($.m.$), Se2 ($.m.$), Se3 ($m.$), and Se4 ($mm2$)). The structure consists of one-dimensional chains of $^1\infty[\text{Th}(\text{Se})_3(\text{Se}_2)_2]^{6-}$ separated by Ba^{2+} cations (Fig. 1). These one-dimensional chains run along the b -axis. Each Th atom in these chains is coordinated to two Se–Se pairs (Se1–Se1 and Se3–Se3), two Se2 atoms, and two Se4 atoms to give rise to a pseudooctahedral geometry around Th (Fig. 2). The geometry of the Th polyhedron in the structure of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ is similar to the An polyhedra in the structures of Ba_2AnS_6 (An = Th and U) [19] but the connectivity of these polyhedra is very different (Fig. 4). Th atoms in $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ are connected to each other through Se4 atoms in the b -direction forming a one-dimensional chain whereas in the structure of Ba_2AnS_6 , the AnS_8 polyhedra share two corners along the a and b axes to result in a two-dimensional structure.

The Se–Se distances of 2.3737(9) and 2.3771(9) Å in this structure are typical for Se–Se single bonds of Se_2^{2-} units, for example in KAuSe_5 (2.362(1) to 2.343(1) Å) [46], $\text{Ba}_8\text{PdU}_2\text{Se}_{12}(\text{Se}_2)_2$ (2.392(1) and 2.407(1) Å) [47], $\text{Cs}_4\text{Ge}_2\text{Se}_8$ (2.350 Å) [48], CsAuSe_3 (2.384 Å) [49], KU_2SbSe_8 (2.356(5) to 2.375(4) Å) [50], USe_3 (2.361 Å) [51], and $\text{RbPdCu}(\text{Se}_2)(\text{Se}_3)$ (2.338(2) Å) [52]. The Th–Se distances of 2.9299(4)–3.0496(5) Å are comparable with Th^{4+} –Se distances in related compounds (Table 3). Hence, charge balance of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ is achieved as $3 \times \text{Ba}^{2+}$, $1 \times \text{Th}^{4+}$, $3 \times \text{Se}^{2-}$, and $2 \times \text{Se}_2^{2-}$.

The Ba1 atoms in $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ are surrounded by seven Se atoms in a distorted monocapped trigonal-prismatic fashion whereas the Ba2 atoms are surrounded by nine Se atoms in a tricapped trigonal-prismatic fashion (Fig. 3). The Ba–Se distances (3.2599(5) to 3.5292(5) Å) in the BaSe_7 and BaSe_9 polyhedra are normal. The BaSe_9 polyhedron in this structure is very similar to that in the structure of BaThTe_4 [53].

3.2 Optical study

The optical absorption spectrum collected at 298 K on a thin single crystal of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ (Fig. 5) shows a band gap transition at 1.96(2) eV, consistent with its dark red color. Analysis of the square and square root of the absorptivity (α) as a function of energy (Fig.6) gives a direct band gap of 1.99(2) eV and an indirect band gap of 1.95(2) eV.

3.3 Theoretical calculations

The total and partial density of states (DOS) of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ are presented in Fig. 7. From the total density of states (upper plot of Fig. 7), $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ is found to be a semiconductor with a band gap of 1.5 eV, compared with the experimental value of 1.96 eV. As expected, no sign of spin polarization is detected, as seen by the totally symmetric DOS for the spin up and the spin down. Also, the top of the valence states corresponds mainly to Se-p states together with Th-f states whereas the bottom of the conduction states corresponds mainly to Se-p states mixed with Ba-d states.

4. Conclusions

The compound $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ has been synthesized in approximately 20 wt% yield by solid-state methods at 1173 K. The dark-red compound crystallizes in a new structure type with two formula units in the noncentrosymmetric space group $C_{2v}^{20}-Imm2$ of the orthorhombic crystal system with cell constants $a = 12.4213(1)$, $b = 5.7911(1)$, and $c = 9.5039(1)$ Å. Its crystal structure features one dimensional chains of ${}^1_\infty[\text{Th}(\text{Se})_3(\text{Se}_2)_2^{6-}]$ separated by Ba^{2+} cations. Each Th atom in these chains is coordinated to two Se-Se single-bonded pairs and four Se atoms to give rise to a pseudooctahedral geometry around Th. The Th-Se distances are consistent with those in a number of Th^{4+} compounds and hence charge balance of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ is achieved as $3 \times \text{Ba}^{2+}$, $1 \times \text{Th}^{4+}$, $3 \times \text{Se}^{2-}$, and $2 \times \text{Se}_2^{2-}$. Analysis of the square and square root of the absorptivity (α) as a function of energy gives a direct band gap of 1.99(2) eV and an indirect band gap of 1.95(2) eV. DFT calculations indicate that the compound is a semiconductor and predict a band gap of 1.5 eV. The top of the valence states corresponds mainly to Se-p states

together with Th-f states whereas the bottom of the conduction states corresponds mainly to Se-p states mixed with Ba-d states.

Acknowledgments

Use was made of the IMSERC X-ray Facility at Northwestern University, supported by the International Institute of Nanotechnology (IIN). S. L. acknowledges HPC resources from GENCI-CCRT/CINES (Grant x2015-085106). Parts of the calculations were performed in the Computing Centre of the Slovak Academy of Sciences using the supercomputing infrastructure acquired in project ITMS26230120002 and 26210120002 (Slovak Infrastructure for High-performance Computing) supported by the Research and Development Operational Programme funded by the ERDF. C.D.M. was supported by the U.S. Department of Energy, Office of Basic Energy Sciences, under Contract DE-AC02-06CH11357.

Appendix A. Supporting information

Crystallographic data in cif format for $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ have been deposited with FIZ Karlsruhe as CSD number 429804. These data may be obtained free of charge by contacting FIZ Karlsruhe at +497247808666 (fax) or crysdata@fiz-karlsruhe.de (email).

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Table 1Crystallographic data and structure refinement details for $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$.

$\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$	
Space group	$C_{2v}^{20} - Imm2$
a (Å)	12.4213(2)
b (Å)	5.7911(1)
c (Å)	9.5039(1)
V (Å ³)	683.65(2)
Z	2
ρ (g cm ⁻³)	5.814
μ (mm ⁻¹)	37.95
$R(F)^b$	0.008
$R_w(F_o^2)^c$	0.017

^a $\lambda = 0.71073$ Å, $T = 100(2)$ K.^b $R(F) = \Sigma \left| |F_o| - |F_c| \right| / \Sigma |F_o|$ for $F_o^2 > 2\sigma(F_o^2)$.^c $R_w(F_o^2) = \{\Sigma [w(F_o^2 - F_c^2)^2] / \Sigma w F_o^4\}^{1/2}$. For $F_o^2 < 0$, $w^{-1} = \sigma^2(F_o^2)$; for $F_o^2 \geq 0$, $w^{-1} = \sigma^2(F_o^2)$.

Table 2Selected interatomic lengths (Å) for Ba₃ThSe₃(Se₂)₂.

Ba ₃ ThSe ₃ (Se ₂) ₂	
Th1–Se1	3.0496(5) × 2
Th1–Se2	2.9299(5) × 2
Th1–Se3	3.0119(5) × 2
Th1–Se4	2.9522(1) × 2
Ba1–Se1	3.5292(5)
Ba1–Se2	3.2599(5)
	3.2744(2) × 2
Ba1–Se3	3.3270(3) × 2
Ba1–Se4	3.2743(3)
Ba2–Se1	3.3070(3) × 4
Ba2–Se2	3.3419(5) × 2
Ba2–Se3	3.3290(6) × 2
Ba2–Se4	3.3028(8)
Se1–Se1	2.3737(9)
Se3–Se3	2.3771(9)
Th1•••Th1	5.7911(1) × 2

Table 3

Th–Se and Se–Se interactions in some related compounds with 8-coordinated Th atoms^a.

Compound	Structure	Th–Se (Å)	Se–Se (Å)	Th Geometry	Ref.
Ba ₃ ThSe ₃ (Se ₂) ₂	1D	2.930(1)–3.050(1)	2.374(1) 2.377(1)	8, poct	this work
SrTh ₂ Se ₅ ^b	3D	2.820(2)–3.116(2)	-	8, bctp	[18]
KTh ₂ Se ₆	Layered	2.962(1)–3.015(1)	2.727(1), 2.907(1)	8, bctp	[15]
CsTh ₂ Se ₆	Layered	2.959(1)–3.006(1)	2.698(3), 2.924(3)	8, bctp	[17]
RbTh ₂ Se ₆	Layered	2.965(1)–3.014(1)	2.728(1), 2.906(1)	8, bctp	[15]
Th ₂ GeSe ₅ ^c	3D	2.959(1)–3.017(1)	-	8, bctp	[54]
Rb ₂ Th ₇ Se ₁₅ ^d	3D	2.879(1)–3.124(1)	-	8, d-sqap	[55]
ThMnSe ₃	3D	2.931(1)–3.161(1)	-	8, bctp	[21]

^aSome distances have been rounded for comparison. All the compounds contain Th⁴⁺.^bStructure also contains seven-coordinate Th atom.^cStructure also contains nine-coordinate Th atom.^dStructure also contains seven- and eight-coordinate (unknown geometry) Th atom.

d = distorted, poct = pseudo-octahedral, bctp = bicapped trigonal prismatic, sqap = square antiprismatic

Figure Captions.

Fig. 1. General view of the crystal structure of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ projected along the b -axis.

Fig. 2. Local coordination environment of Th atoms in the $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ structure.

Fig. 3. Local coordination environment of Ba1 and Ba2 atoms in the $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ structure.

Fig. 4. Comparison of (a) the ${}^2_\infty[\text{AnS}_6^{4-}]$ layers in the Ba_2AnS_6 (An = Th, U) [19] structure with (b) the ${}^1_\infty[\text{ThSe}_7^{6-}]$ chains in the $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ structure.

Fig. 5. Optical absorption spectrum of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$.

Fig. 6. Analysis of α^2 and $\alpha^{1/2}$ vs. energy for $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$.

Fig. 7. Total and partial density of states (DOS) of $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$.

Figure 1

Figure 2

Figure 3

Figure 4

Figure 5

Figure 6

Figure 7

Local coordination environment of Th atoms in the $\text{Ba}_3\text{ThSe}_3(\text{Se}_2)_2$ structure